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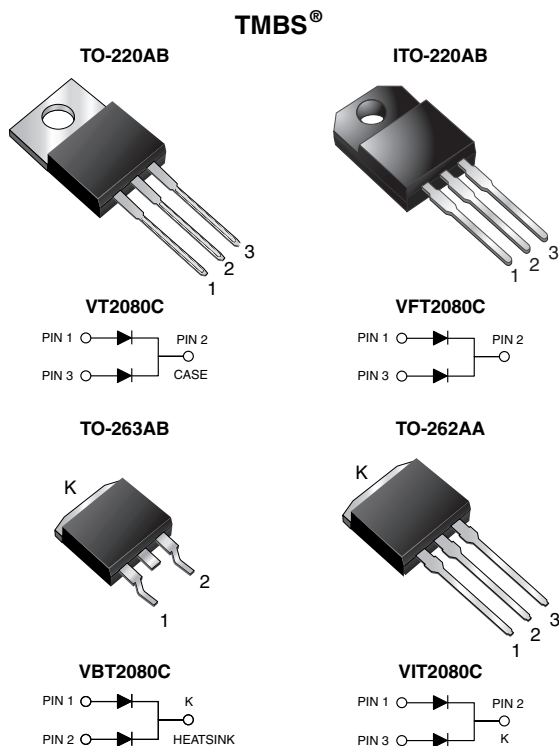
VT2080C-E3, VFT2080C-E3, VBT2080C-E3, VIT2080C-E3

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Vishay General Semiconductor

Dual Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.52 \text{ V}$ at $I_F = 5 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 10 A
V_{RRM}	80 V
I_{FSM}	100 A
V_F at $I_F = 10 \text{ A}$	0.60 V
T_J max.	150 °C
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA
Diode variations	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VT2080C	VFT2080C	VBT2080C	VIT2080C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}			80		V
Maximum average forward rectified current (fig. 1)	per device per diode	$I_{F(AV)}$		20		A
				10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}			100		A
Non-repetitive avalanche energy at $T_J = 25 \text{ °C}$, $L = 60 \text{ mH}$ per diode	E_{AS}			110		mJ
Peak repetitive reverse current at $t_p = 2 \text{ } \mu\text{s}$, 1 kHz, $T_J = 38 \text{ °C} \pm 2 \text{ °C}$ per diode	I_{RRM}			1.0		A
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1 \text{ min}$	V_{AC}			1500		V
Operating junction and storage temperature range	T_J, T_{STG}			-55 to +150		°C



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ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.57	-	V
	$I_F = 10\text{ A}$			0.67	0.81	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.52	-	
	$I_F = 10\text{ A}$			0.60	0.70	
Reverse current per diode	$V_R = 80\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	20	600	μA
		$T_A = 125\text{ }^\circ\text{C}$		10	20	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
 (2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)							
PARAMETER		SYMBOL	VT2080C	VFT2080C	VBT2080C	VIT2080C	UNIT
Typical thermal resistance	per diode	$R_{\theta\text{JC}}$	3.0	6.0	3.0	3.0	$^\circ\text{C/W}$
	per device		2.0	5.0	2.0	2.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	VT2080C-E3/4W	1.88	4W	50/tube	Tube
ITO-220AB	VFT2080C-E3/4W	1.73	4W	50/tube	Tube
TO-263AB	VBT2080C-E3/4W	1.36	4W	50/tube	Tube
TO-263AB	VBT2080C-E3/8W	1.36	8W	800/reel	Tape and reel
TO-262AA	VIT2080C-E3/4W	1.44	4W	50/tube	Tube



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

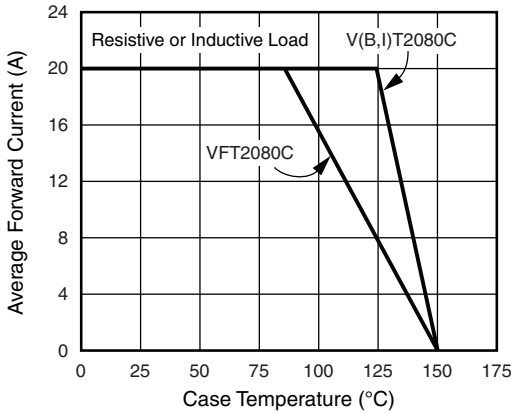


Fig. 1 - Maximum Forward Current Derating Curve

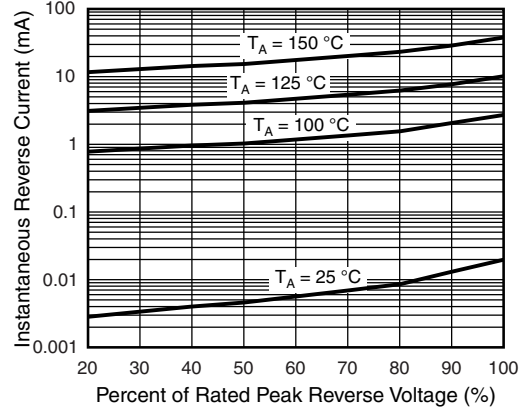


Fig. 4 - Typical Reverse Characteristics Per Diode

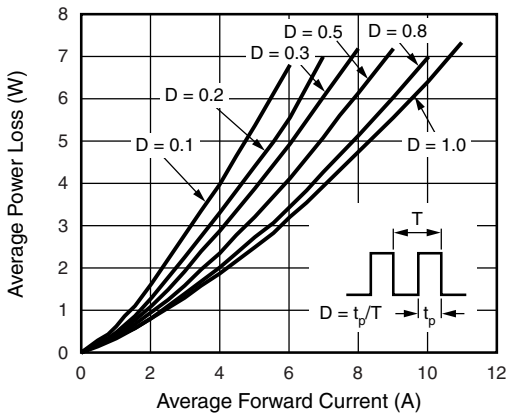


Fig. 2 - Forward Power Loss Characteristics Per Diode

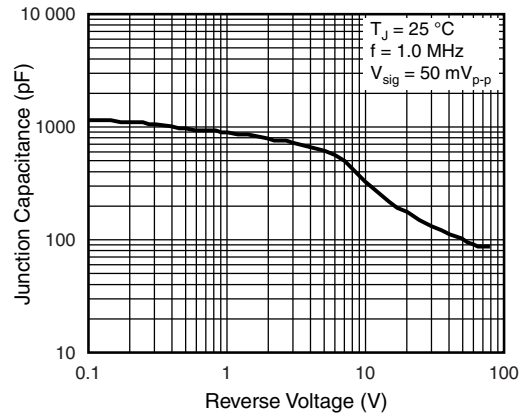


Fig. 5 - Typical Junction Capacitance Per Diode

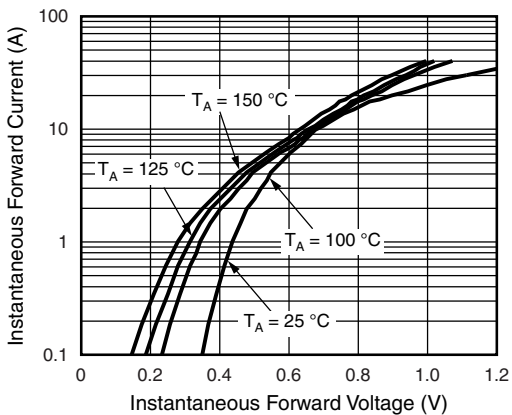


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

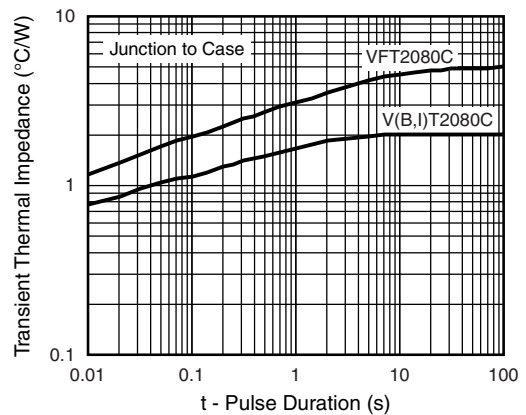
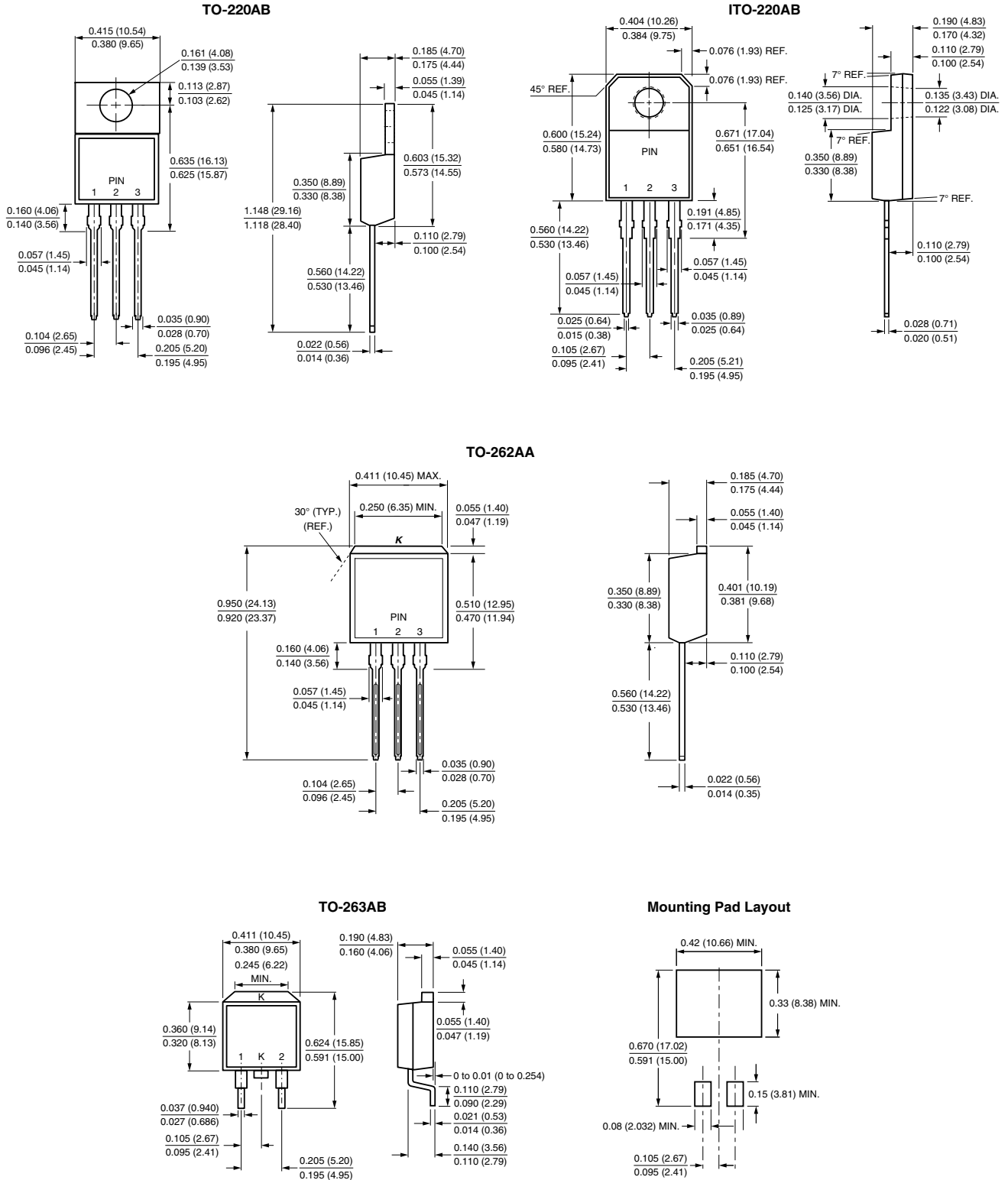


Fig. 6 - Typical Transient Thermal Impedance Per Device



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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